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INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use as many sheets as necessary)</i>		Application Number	
		Filing Date	
		First Named Inventor	Onishi
		Art Unit	
		Examiner Name	
		Attorney Docket Number	SO-1
Sheet	1	of	2

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Sheet 1 of 2

U. S. PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS

Examiner Signature /Rodney McDonald/ Date 01/01/2023

Signature /Rodney McDonald/ **Considered** 01/24/2007

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NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			
RM	1	Ohnishi et al, Chemical Vapor Deposition of Single-Crystalline ZnO Film with Smooth Surface on Intermediately Sputtered ZnO Thin Film on Sapphire,			
		Japanese Jorn. of App. Physics, vol. 17, no. 5, May 1978, pp. 773-778			
RM	2	Onishi et al, Transparent and Highly Oriented ZnO films Grown at Low Temperature by Sputtering with a Modified Sputter Gun,			
		Applied Phys. Letters, vol. 38 no. 6 March 1981			

Examiner Signature	/Rodney McDonald/	Date Considered	01/24/2007
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